NSN 5961-00-444-3041

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Inclosure Material:
Metal
Overall Length:
1.573 inches
Terminal Length:
0.500 inches
Overall Height:
0.380 inches
Overall Width:
1.050 inches
Mounting Facility Quantity:
2
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-3
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
36.0 regulator voltage
Voltage Tolerance In Percent:
-5.0/+5.0
Current Rating Per Characteristic:
350.00 milliamperes all primaries horsepower metric and 1.32 amperes repetitive peak forward current
Power Rating Per Characteristic:
50.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Special Features:
Cathode pins internally connected; junction pattern arrangement: pn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 pin and 1 case
Specification Data:
81349-mil-s-19500/114 government specification

N/a

Shelf Life:

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Demilitarization:

No

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